

L Number	Hits	Search Text	DB	Time stamp
1	4789	MIS near3 transistor) (metal near insulator near semiconductor near transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/14 16:48
2	3272534	trench\$2 recess\$2 opening	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/14 16:49
3	85592	electric near charg\$3) (trap\$3 near electric) (trap\$3 near charg\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/14 16:50
4	119	(MIS near3 transistor) (metal near insulator near semiconductor near transistor) and (trench\$2 recess\$2 opening) and (electric near charg\$3) (trap\$3 near electric) (trap\$3 near charg\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/14 16:50